Device Modeling Report

COMPONENTS:
DIODE/ GENERAL PURPOSE RECTIFIER/ PROFESSIONAL
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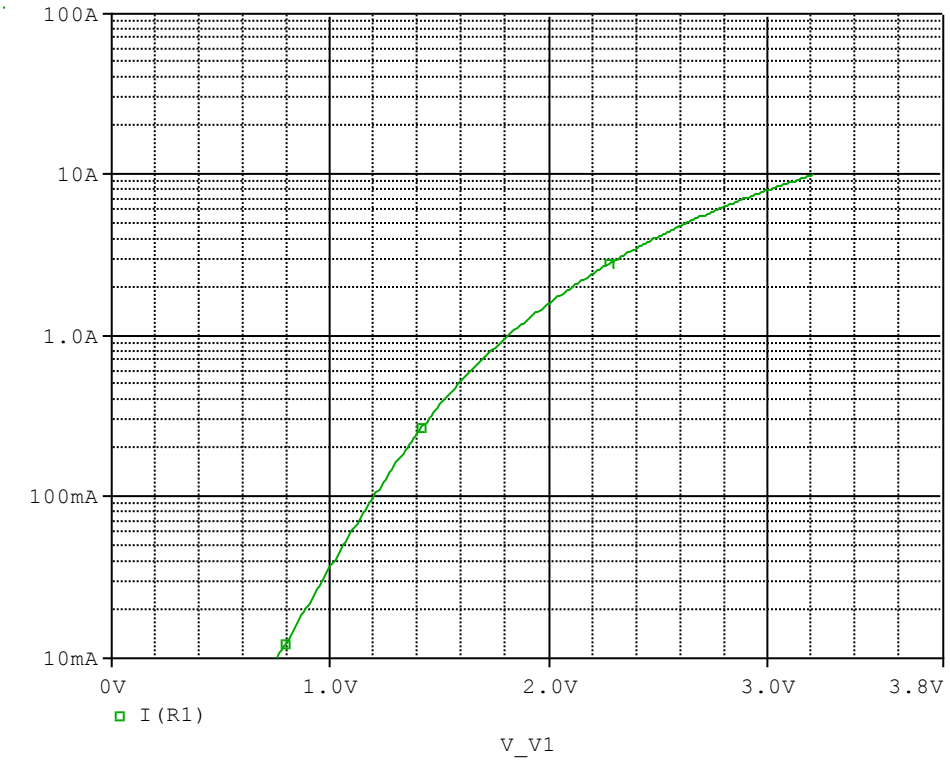
Bee Technologies Inc.

DIODE MODEL PARAMETERS

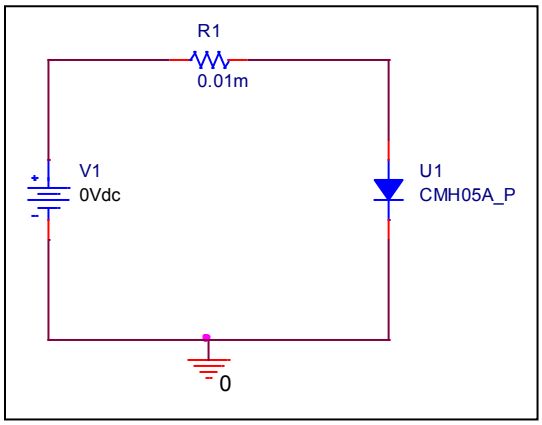
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

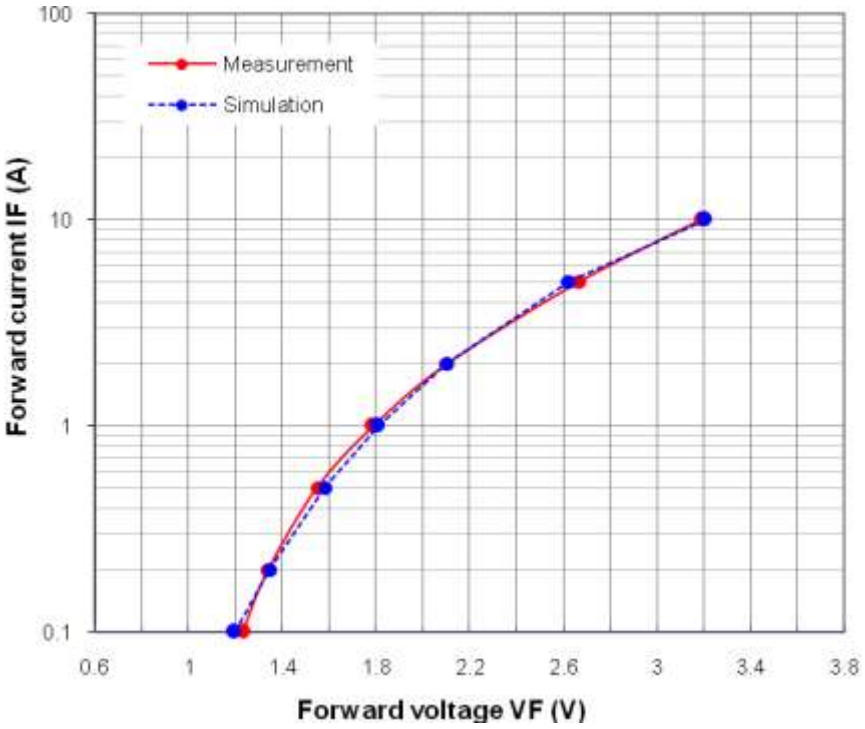


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

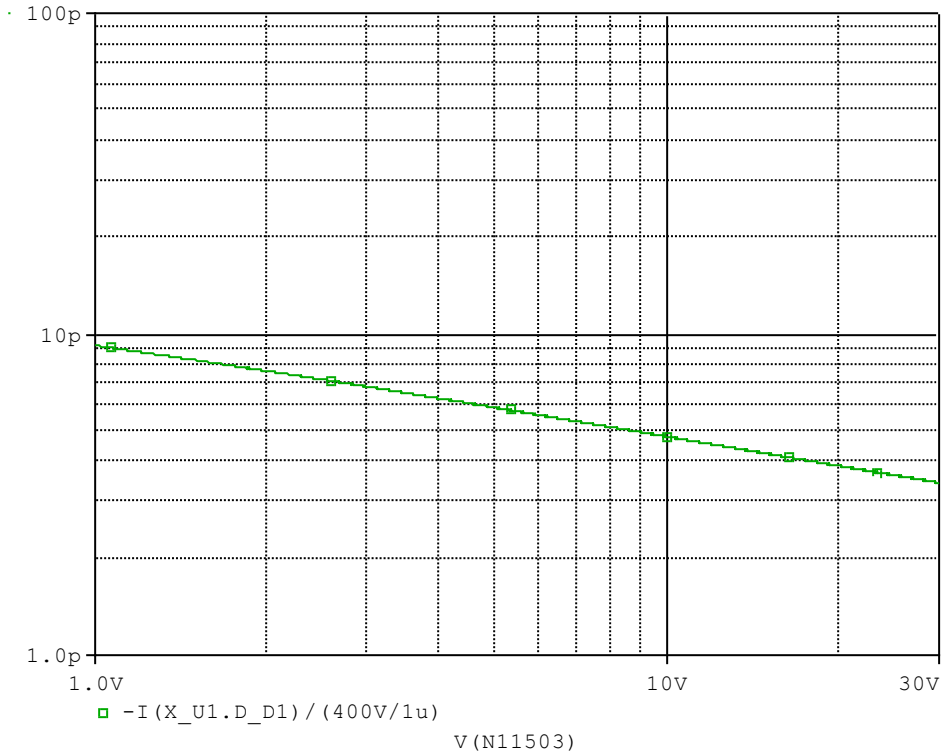


Simulation Result

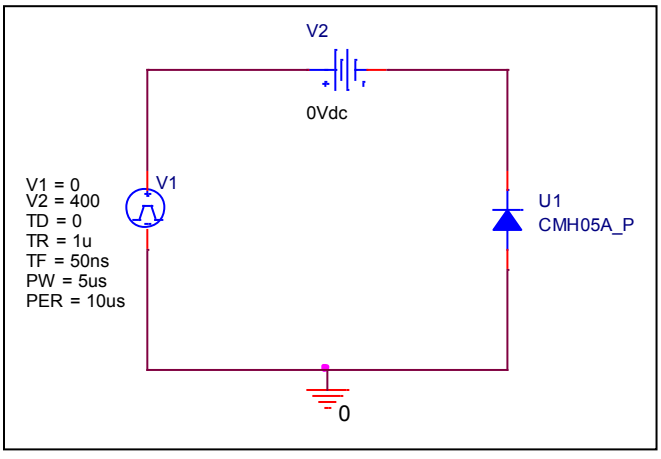
Ifwd (A)	Vfwd (V)		%Error
	Measurement	Simulation	
0.1	1.232	1.196	-2.90
0.2	1.337	1.346	0.68
0.5	1.549	1.581	2.06
1	1.787	1.809	1.24
2	2.104	2.101	-0.13
5	2.668	2.624	-1.64
10	3.187	3.206	0.59

Capacitance Characteristic

Circuit Simulation Result

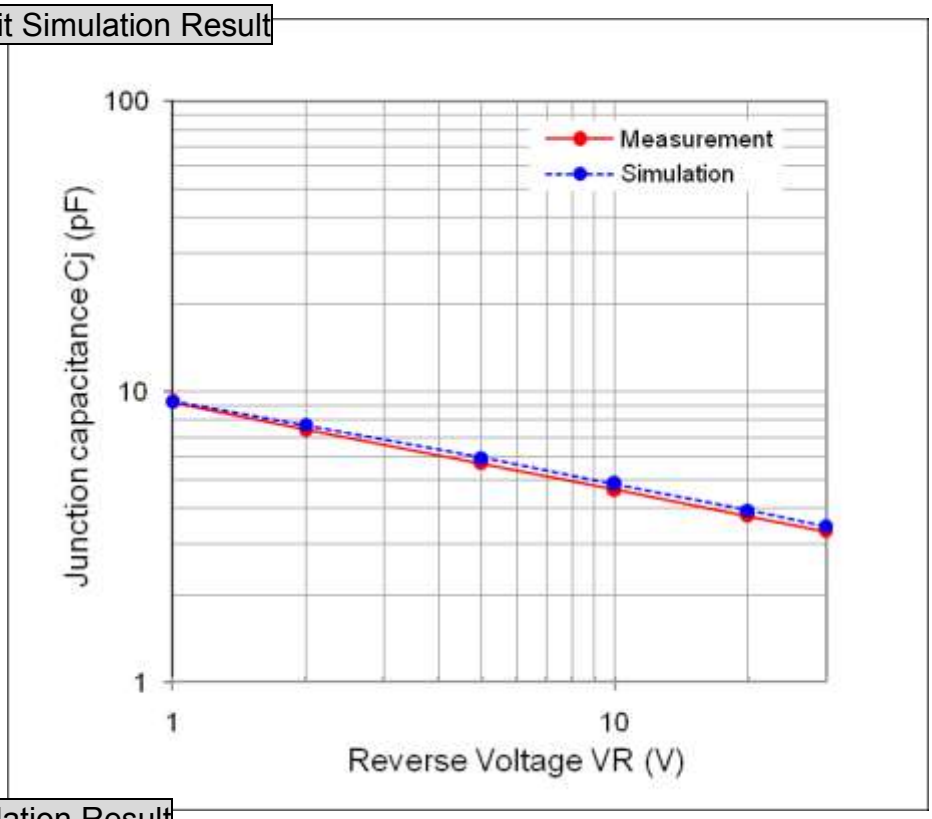


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

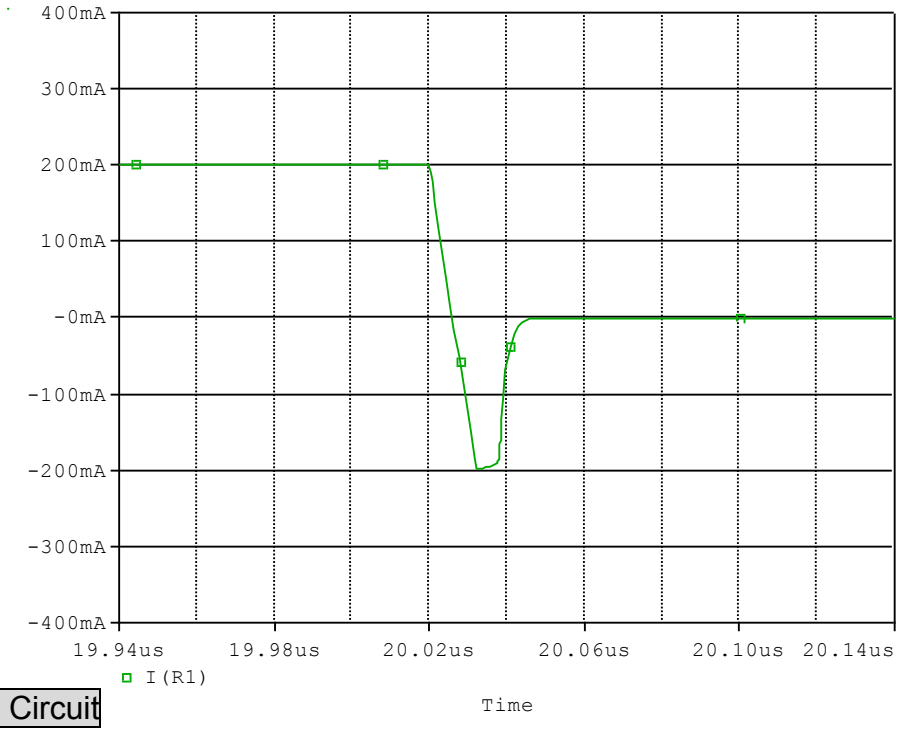


Simulation Result

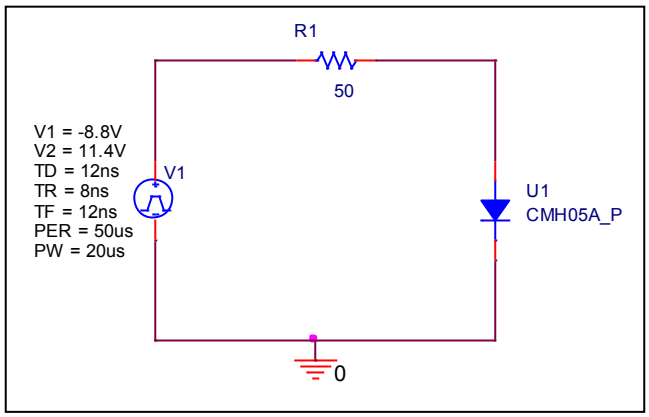
Vrev (V)	Cj (pF)		%Error
	Measurement	Simulation	
1	9.200	9.233	0.36
2	7.400	7.675	3.72
5	5.650	5.908	4.57
10	4.580	4.796	4.71
20	3.720	3.890	4.57
30	3.300	3.443	4.33

Reverse Recovery Characteristic

Circuit Simulation Result



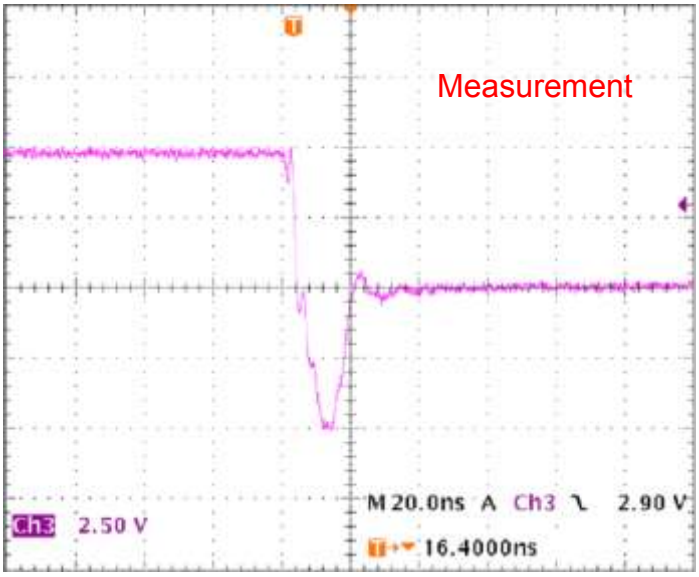
Evaluation Circuit



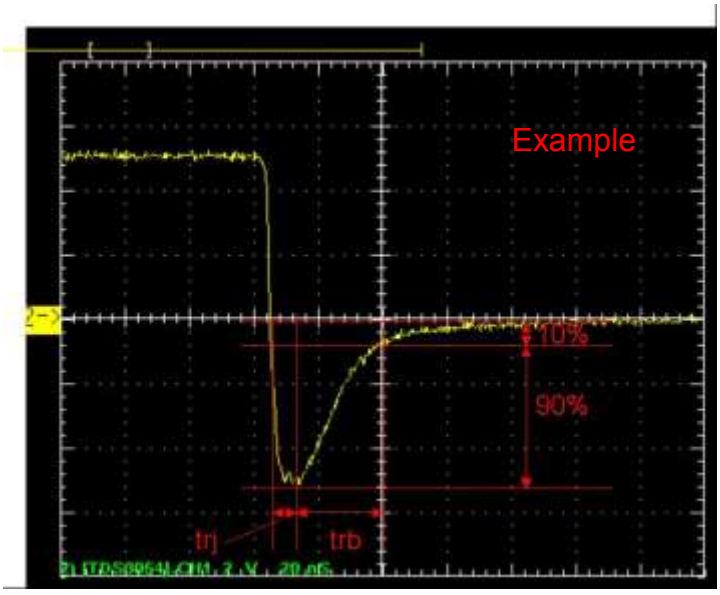
Compare Measurement vs. Simulation

		Measurement	Simulation	%Error
Trj	**ns**	**9.20**	**9.02**	**-1.91**
Trb	**ns**	**6.40**	**6.24**	**-2.49**
Trr	**ns**	**15.60**	**15.27**	**-2.14**

Reverse Recovery Characteristic Reference



Trj =9.20(ns)
Trb= 6.40(ns)
Conditions: Ifwd=0.2A,Irev=0.2A, Rl=50



Relation between trj and trb